## NSN 5962-01-298-6805

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View Online at https://aerobasegroup.com/nsn/5962-01-298-6805

Body Length:
1.280 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
I.02 watts
Operating Tempurature Range:
55.0/+125.0 degrees celsius
Storage Tempurature Range:
65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and programmable and bipolar
nclosure Material:
Ceramic
nclosure Configuration:
Dual-in-line
Output Logic Form:
Fransistor-transistor logic
nput Circuit Pattern:
14 input
Case Outline Source And Designator:
D-9 mil-m-38510
Ferminal Surface Treatment:
Solder
/oltage Rating And Type Per Characteristic:
0.3 volts power source and 7.0 volts power source
Fime Rating Per Chacteristic:
25.00 nanoseconds propagation delay time, low to high level output and 25.00 nanoseconds propagation delay time, high to low level
putput
Memory Device Type:
Rom
Memory Capacity:
Jnknown
Fest Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Ferminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a

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**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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